

In The United States Patent & Trademark Office

5	Applicant	:	Martin E. Kordesch, et al.	
	Serial No.	:	09/682,151	
10	Filed	:	27 July 2001	Examiner: Jerome Jackson, Jr.
15	For	:	CONTACT METHOD FOR THIN (SILICON CARBIDE EPITAXIAL ()) LAYER AND SEMICONDUCTOR () DEVICES FORMED BY THOSE () METHODS ()	Art Unit: 2815
20	AMENDMENT			
	Commission Mail Stop: A P. O. Box 14	Amend		

Dear Sir:

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In response to the Office Action mailed June 10, 2005, please amend the

30 application as follows.

Alexandria, VA 22313-1450